



HIGH-SPEED 3.3V 16/8K X 9 SYNCHRONOUS PIPELINED DUAL-PORT STATIC RAM

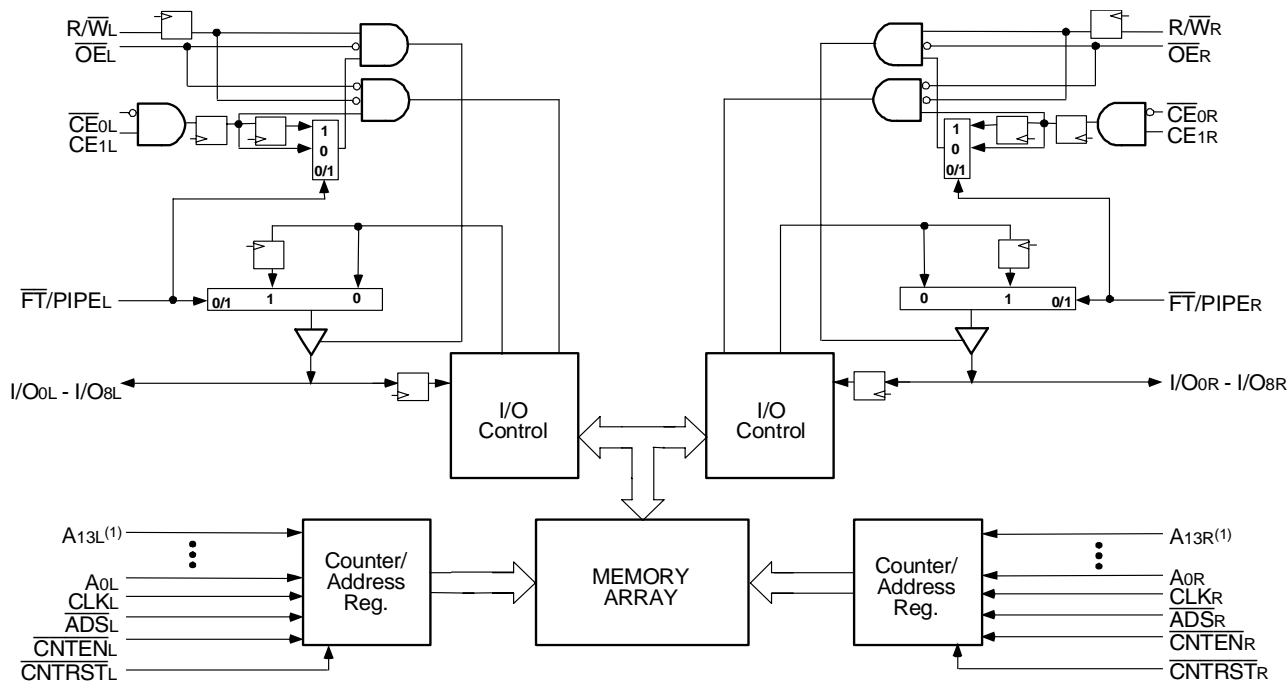
IDT70V9169/59L

Features:

- ♦ True Dual-Ported memory cells which allow simultaneous access of the same memory location
- ♦ High-speed clock to data access
 - Commercial: 6.5/7.5/9ns (max.)
 - Industrial: 7.5ns (max.)
- ♦ Low-power operation
 - IDT70V916/59L/59L
 - Active: 450mW (typ.)
 - Standby: 1.5mW (typ.)
- ♦ Flow-Through or Pipelined output mode on either port via the $\overline{\text{FT}}/\text{PIPE}$ pins
- ♦ Counter enable and reset features
- ♦ Dual chip enables allow for depth expansion without additional logic

- ♦ Full synchronous operation on both ports
 - 3.5ns setup to clock and 0ns hold on all control, data, and address inputs
 - Data input, address, and control registers
 - Fast 6.5ns clock to data out in the Pipelined output mode
 - Self-timed write allows fast cycle time
 - 10ns cycle time, 100MHz operation in Pipelined output mode
- ♦ Separate upper-byte and lower-byte controls for multiplexed bus and bus matching compatibility
- ♦ LVTTTL-compatible, single 3.3V ($\pm 0.3\text{V}$) power supply
- ♦ Industrial temperature range (-40°C to $+85^{\circ}\text{C}$) is available for 83 MHz
- ♦ Available in a 100-pin Thin Quad Flatpack (TQFP) and 100-pin fine pitch Ball Grid Array (fpBGA) packages.

Functional Block Diagram



5655 drw 01

NOTE:

1. A_{13} is a NC for IDT70V9159.

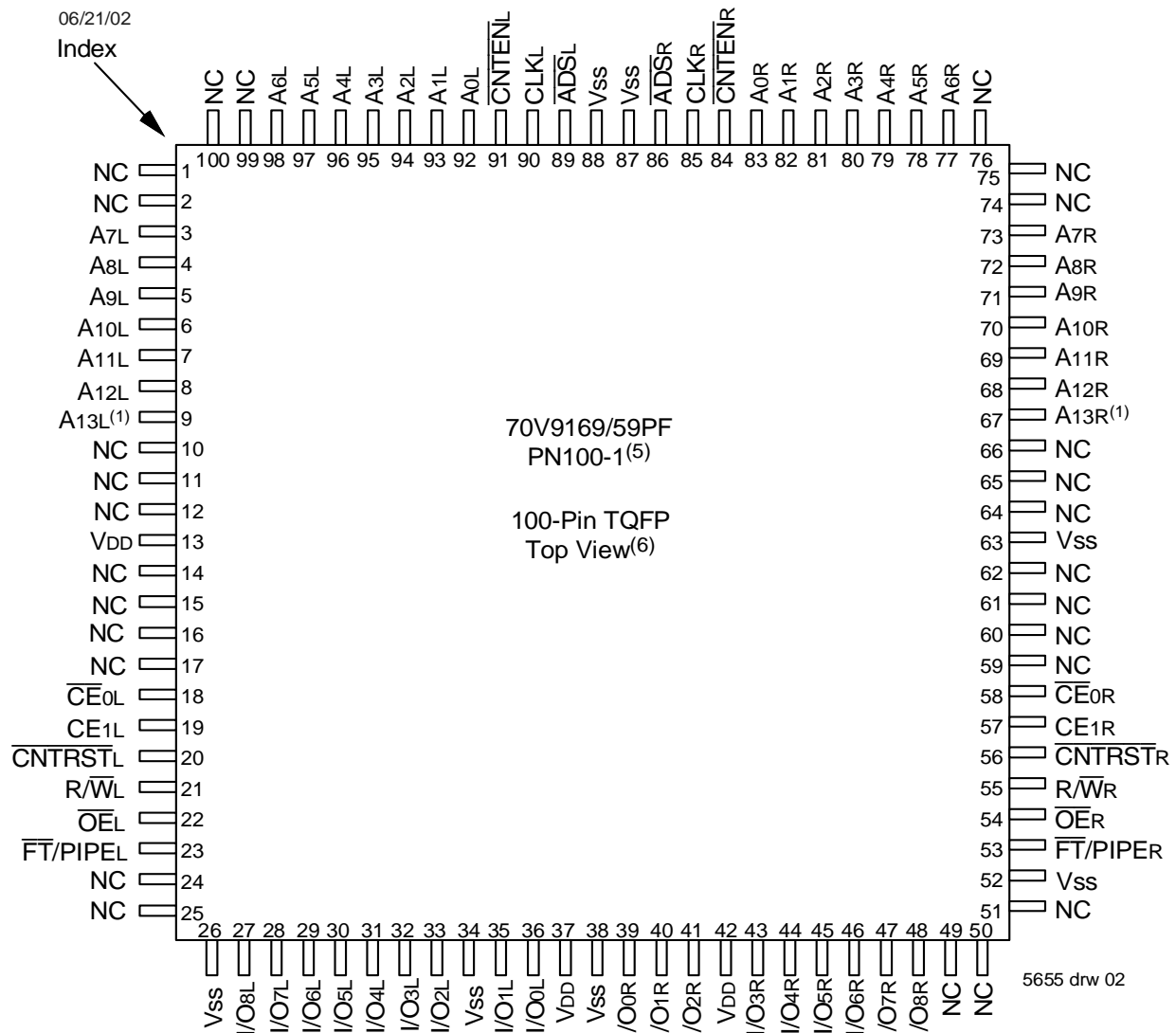
AUGUST 2003

Description:

The IDT70V9169/59 is a high-speed 16/8K x 9 bit synchronous Dual-Port RAM. The memory array utilizes Dual-Port memory cells to allow simultaneous access of any address from both ports. Registers on control, data, and address inputs provide minimal setup and hold times. The timing latitude provided by this approach allows systems to be designed with very short cycle times.

With an input data register, the IDT70V9169/59 has been optimized for applications having unidirectional or bidirectional data flow in bursts. An automatic power down feature, controlled by $\overline{CE_0}$ and CE_1 , permits the on-chip circuitry of each port to enter a very low standby power mode. Fabricated using IDT's CMOS high-performance technology, these devices typically operate on only 450mW of power.

Pin Configurations^(1,2,3,4)



NOTES:

1. A13 is a NC for IDT70V9159.
2. All VDD pins must be connected to power supply.
3. All VSS pins must be connected to ground supply.
4. Package body is approximately 14mm x 14mm x 1.4mm.
5. This package code is used to reference the package diagram.
6. This text does not indicate orientation of the actual part-marking.

Pin Configurations(cont'd)^(1,2,3,4)

70V9169/59PF
BF100⁽⁵⁾

100-Pin fpBGA
Top View⁽⁶⁾

06/21/02

A1 A6R	A2 A9R	A3 A12R	A4 NC	A5 VSS	A6 VSS	A7 NC	A8 R/W _R	A9 VSS	A10 NC
B1 A4R	B2 A5R	B3 A8R	B4 A10R	B5 NC	B6 NC	B7 NC	B8 O _E R	B9 NC	B10 I/O6R
C1 A3R	C2 NC	C3 NC	C4 A7R	C5 NC	C6 CE ₀ R	C7 CE ₁ R	C8 PL/FT _R	C9 I/O7R	C10 I/O3R
D1 A0R	D2 CLK _R	D3 A1R	D4 A2R	D5 A11R	D6 A13R ⁽¹⁾	D7 CNTRST _R	D8 I/O8R	D9 I/O5R	D10 I/O1R
E1 VSS	E2 ADS _R	E3 CNTEN _R	E4 A1L	E5 ADS _L	E6 VSS	E7 I/O4R	E8 I/O2R	E9 I/O0R	E10 VDD
F1 VSS	F2 CLK _L	F3 A0L	F4 A3L	F5 VDD	F6 VSS	F7 VDD	F8 I/O2L	F9 I/O1L	F10 I/O0L
G1 CNTEN _L	G2 NC	G3 A5L	G4 A12L	G5 NC	G6 R/W _L	G7 NC	G8 I/O4L	G9 VSS	G10 I/O3L
H1 A2L	H2 A4L	H3 A9L	H4 A13L ⁽¹⁾	H5 NC	H6 CE ₁ L	H7 NC	H8 I/O7L	H9 I/O6L	H10 I/O5L
J1 NC	J2 A7L	J3 A10L	J4 NC	J5 NC	J6 NC	J7 O _E L	J8 VSS	J9 VSS	J10 I/O8L
K1 A6L	K2 A8L	K3 A11L	K4 NC	K5 VDD	K6 VDD	K7 CE ₀ L	K8 CNTRST _L	K9 PL/FT _L	K10 NC

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NOTES:

1. A13 is a NC for IDT70V9159.
2. All VDD pins must be connected to power supply.
3. All VSS pins must be connected to ground supply.
4. Package body is approximately 10mm x 10mm x 1.4mm with 0.8mm ball pitch.
5. This package code is used to reference the package diagram.
6. This text does not indicate orientation of the actual part-marking.

Pin Names

Left Port	Right Port	Names
\overline{CE}_{0L} , CE_{1L}	\overline{CE}_{0R} , CE_{1R}	Chip Enables
R/\overline{W}_L	R/\overline{W}_R	Read/Write Enable
\overline{OE}_L	\overline{OE}_R	Output Enable
$A_{0L} - A_{13L}^{(1)}$	$A_{0R} - A_{13R}^{(1)}$	Address
$I/O_{0L} - I/O_{8L}$	$I/O_{0R} - I/O_{8R}$	Data Input/Output
CLK_L	CLK_R	Clock
\overline{ADS}_L	\overline{ADS}_R	Address Strobe
\overline{CNTEN}_L	\overline{CNTEN}_R	Counter Enable
\overline{CNTRST}_L	\overline{CNTRST}_R	Counter Reset
$\overline{FT}/PIPE_L$	$\overline{FT}/PIPE_R$	Flow-Through/Pipeline
V_{DD}		Power (3.3V)
V_{SS}		Ground (0V)

5655 tbl 01

NOTE:

1. A13 is a NC for IDT70V9159.

Truth Table I—Read/Write and Enable Control^(1,2,3)

\overline{OE}	CLK	\overline{CE}_0	CE_1	R/\overline{W}	I/O_{0-8}	Mode
X	↑	H	X	X	High-Z	Deselected—Power Down
X	↑	X	L	X	High-Z	Deselected—Power Down
X	↑	L	H	L	DATA _{IN}	Write
L	↑	L	H	H	DATA _{OUT}	Read
H	X	L	H	X	High-Z	Outputs Disabled

5655 tbl 02

NOTES:

1. "H" = V_{IH} , "L" = V_{IL} , "X" = Don't Care.
2. \overline{ADS} , \overline{CNTEN} , \overline{CNTRST} = X.
3. \overline{OE} is an asynchronous input signal.

Truth Table II—Address Counter Control^(1,2)

External Address	Previous Internal Address	Internal Address Used	CLK	\overline{ADS}	\overline{CNTEN}	\overline{CNRST}	I/O ⁽³⁾	MODE
An	X	An	↑	L ⁽⁴⁾	X	H	D _{IO} (n)	External Address Used
X	An	An + 1	↑	H	L ⁽⁵⁾	H	D _{IO} (n+1)	Counter Enabled—Internal Address generation
X	An + 1	An + 1	↑	H	H	H	D _{IO} (n+1)	External Address Blocked—Counter disabled (An + 1 reused)
X	X	A0	↑	X	X	L ⁽⁴⁾	D _{IO} (0)	Counter Reset to Address 0

NOTES:

5655 tbl 03

- "H" = V_{IH}, "L" = V_{IL}, "X" = Don't Care.
- $\overline{CE0}$, \overline{LB} , \overline{UB} , and \overline{OE} = V_{IL}; CE₁ and R \overline{W} = V_{IH}.
- Outputs configured in Flow-Through Output mode: if outputs are in Pipelined mode the data out will be delayed by one cycle.
- \overline{ADS} and \overline{CNRST} are independent of all other signals including $\overline{CE0}$, CE₁, \overline{UB} and \overline{LB} .
- The address counter advances if \overline{CNTEN} = V_{IL} on the rising edge of CLK, regardless of all other signals including $\overline{CE0}$, CE₁, \overline{UB} and \overline{LB} .

Recommended Operating Temperature and Supply Voltage

Grade	Ambient Temperature ⁽¹⁾	GND	V _{DD}
Commercial	0°C to +70°C	0V	3.3V ± 0.3V
Industrial	-40°C to +85°C	0V	3.3V ± 0.3V

5655 tbl 04

NOTES:

- This is the parameter T_A. This is the "instant on" case temperature.

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{DD}	Supply Voltage	3.0	3.3	3.6	V
V _{SS}	Ground	0	0	0	V
V _{IH}	Input High Voltage	2.0	—	V _{DD} +0.3V ⁽²⁾	V
V _{IL}	Input Low Voltage	-0.3 ⁽¹⁾	—	0.8	V

5655 tbl 05

NOTES:

- V_{IL} ≥ -1.5V for pulse width less than 10 ns.
- V_{TERM} must not exceed V_{DD}+0.3V.

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Commercial & Industrial	Unit
V _{TERM} ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
T _{BIAS}	Temperature Under Bias	-55 to +125	°C
T _{STG}	Storage Temperature	-65 to +150	°C
I _{OUT}	DC Output Current	50	mA

5655 tbl 06

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{TERM} must not exceed V_{DD} + 0.3V for more than 25% of the cycle time or 10ns maximum, and is limited to ≤ 20mA for the period of V_{TERM} ≥ V_{DD} + 0.3V.

Capacitance⁽¹⁾(T_A = +25°C, f = 1.0MHz)

Symbol	Parameter	Conditions ⁽²⁾	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 3dV	9	pF
C _{OUT} ⁽³⁾	Output Capacitance	V _{OUT} = 3dV	10	pF

5655 tbl 07

NOTES:

- These parameters are determined by device characterization, but are not production tested.
- 3dV references the interpolated capacitance when the input and output switch from 0V to 3V or from 3V to 0V.
- C_{OUT} also references C_{I/O}.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range ($V_{DD} = 3.3V \pm 0.3V$)

Symbol	Parameter	Test Conditions	70V9169/59L		Unit
			Min.	Max.	
$ I_{LI} $	Input Leakage Current ⁽¹⁾	$V_{DD} = 3.6V, V_{IN} = 0V$ to V_{DD}	—	5	μA
$ I_{LO} $	Output Leakage Current	$\overline{CE} = V_{IH}$ or $CE_1 = V_{IL}, V_{OUT} = 0V$ to V_{DD}	—	5	μA
V_{OL}	Output Low Voltage	$I_{OL} = +4mA$	—	0.4	V
V_{OH}	Output High Voltage	$I_{OH} = -4mA$	2.4	—	V

NOTE:

5655 tbl 08

1. At $V_{DD} \leq 2.0V$ input leakages are undefined.

DC Electrical Characteristics Over the Operating Temperature Supply Voltage Range⁽³⁾ ($V_{DD} = 3.3V \pm 0.3V$)

Symbol	Parameter	Test Condition	Version	70V9169/59L6 Com'l Only		70V9169/59L7 Com'l & Ind		70V9169/59L9 Com'l Only		Unit
				Typ. ⁽⁴⁾	Max.	Typ. ⁽⁴⁾	Max.	Typ. ⁽⁴⁾	Max.	
I_{DD}	Dynamic Operating Current (Both Ports Active)	\overline{CE}_L and $\overline{CE}_R = V_{IL}$, Outputs Disabled, $f = f_{MAX}$ ⁽¹⁾	COM'L L	175	330	155	280	135	230	mA
			IND L	—	—	155	330	—	—	
ISB1	Standby Current (Both Ports - TTL Level Inputs)	$\overline{CE}_L = \overline{CE}_R = V_{IH}$ $f = f_{MAX}$ ⁽¹⁾	COM'L L	50	80	40	70	30	60	mA
			IND L	—	—	40	80	—	—	
ISB2	Standby Current (One Port - TTL Level Inputs)	$\overline{CE}^A = V_{IL}$ and $\overline{CE}^B = V_{IH}$ ⁽⁵⁾ Active Port Outputs Disabled, $f = f_{MAX}$ ⁽¹⁾	COM'L L	115	185	105	170	95	155	mA
			IND L	—	—	105	180	—	—	
ISB3	Full Standby Current (Both Ports - CMOS Level Inputs)	Both Ports \overline{CE}_L and $\overline{CE}_R \geq V_{DD} - 0.2V$, $V_{IN} \geq V_{DD} - 0.2V$ or $V_{IN} \leq 0.2V, f = 0$ ⁽²⁾	COM'L L	0.5	3.0	0.5	3.0	0.5	3.0	mA
			IND L	—	—	0.5	3.0	—	—	
ISB4	Full Standby Current (One Port - CMOS Level Inputs)	$\overline{CE}^A \leq 0.2V$ and $\overline{CE}^B \geq V_{DD} - 0.2V$ ⁽⁵⁾ $V_{IN} \geq V_{DD} - 0.2V$ or $V_{IN} \leq 0.2V$, Active Port, Outputs Disabled, $f = f_{MAX}$ ⁽¹⁾	COM'L L	105	175	95	160	85	145	mA
			IND L	—	—	95	175	—	—	

5655 tbl 09

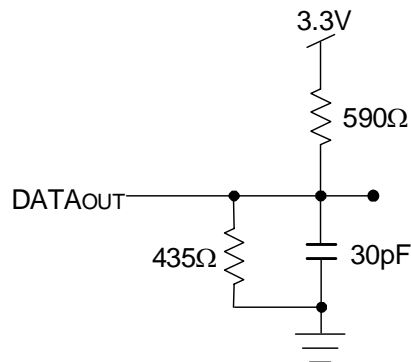
NOTES:

- At $f = f_{MAX}$, address and control lines (except Output Enable) are cycling at the maximum frequency clock cycle of $1/t_{CYC}$, using "AC TEST CONDITIONS" at input levels of GND to 3V.
- $f = 0$ means no address, clock, or control lines change. Applies only to input at CMOS level standby.
- Port "A" may be either left or right port. Port "B" is the opposite from port "A".
- $V_{DD} = 3.3V, T_A = 25^\circ C$ for Typ, and are not production tested. $I_{CC DC}(f=0) = 90mA$ (Typ).
- $\overline{CE}_X = V_{IL}$ means $\overline{CE}_{0X} = V_{IL}$ and $CE_{1X} = V_{IH}$
 $\overline{CE}_X = V_{IH}$ means $\overline{CE}_{0X} = V_{IH}$ or $CE_{1X} = V_{IL}$
 $\overline{CE}_X \leq 0.2V$ means $\overline{CE}_{0X} \leq 0.2V$ and $CE_{1X} \geq V_{DD} - 0.2V$
 $\overline{CE}_X \geq V_{DD} - 0.2V$ means $\overline{CE}_{0X} \geq V_{DD} - 0.2V$ or $CE_{1X} \leq 0.2V$
 "X" represents "L" for left port or "R" for right port.

AC Test Conditions

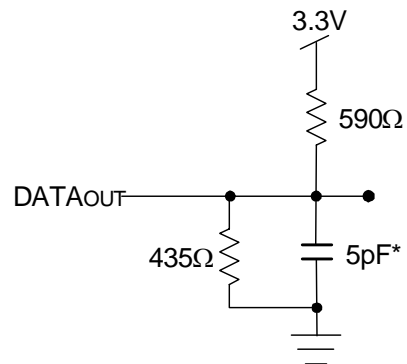
Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	2ns Max.
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	Figures 1, 2 & 3

5655 tbl 10



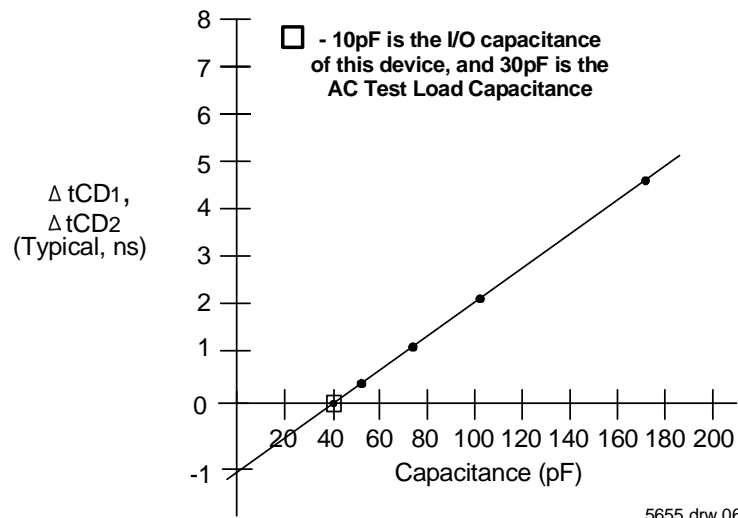
5655 drw 03

Figure 1. AC Output Test load.



5655 drw 04

Figure 2. Output Test Load
(For t_{CKLZ}, t_{CKHZ}, t_{OLZ}, and t_{OHZ}).
*Including scope and jig.



5655 drw 06

Figure 3. Typical Output Derating (Lumped Capacitive Load).

AC Electrical Characteristics Over the Operating Temperature Range (Read and Write Cycle Timing)⁽³⁾ ($V_{DD} = 3.3V \pm 0.3V$, $T_A = 0^\circ C$ to $+70^\circ C$)

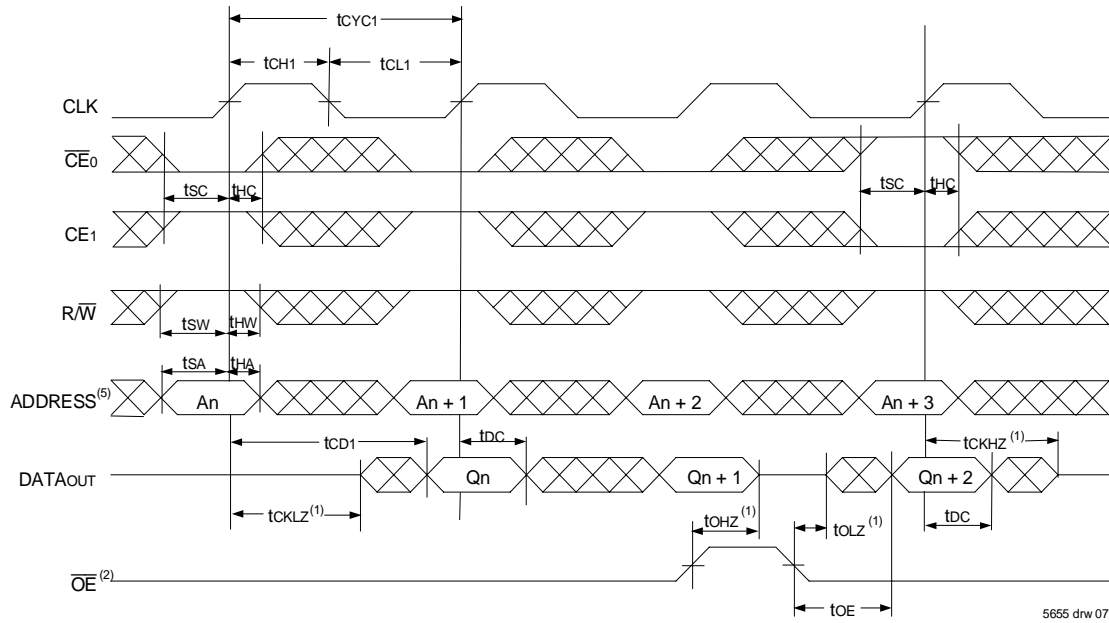
Symbol	Parameter	70V9169/59L6 Com'l Only		70V9169/59L7 Com'l & Ind		70V9169/59L9 Com'l Only		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{CYC1}	Clock Cycle Time (Flow-Through) ⁽²⁾	19	—	22	—	25	—	ns
t _{CYC2}	Clock Cycle Time (Pipelined) ⁽²⁾	10	—	12	—	15	—	ns
t _{CH1}	Clock High Time (Flow-Through) ⁽²⁾	6.5	—	7.5	—	12	—	ns
t _{CL1}	Clock Low Time (Flow-Through) ⁽²⁾	6.5	—	7.5	—	12	—	ns
t _{CH2}	Clock High Time (Pipelined) ⁽²⁾	4	—	5	—	6	—	ns
t _{CL2}	Clock Low Time (Pipelined) ⁽²⁾	4	—	5	—	6	—	ns
t _r	Clock Rise Time	—	3	—	3	—	3	ns
t _f	Clock Fall Time	—	3	—	3	—	3	ns
t _{SA}	Address Setup Time	3.5	—	4	—	4	—	ns
t _{HA}	Address Hold Time	0	—	0	—	1	—	ns
t _{SC}	Chip Enable Setup Time	3.5	—	4	—	4	—	ns
t _{HC}	Chip Enable Hold Time	0	—	0	—	1	—	ns
t _{SB}	Byte Enable Setup Time	3.5	—	4	—	4	—	ns
t _{HB}	Byte Enable Hold Time	0	—	0	—	1	—	ns
t _{SW}	R/W Setup Time	3.5	—	4	—	4	—	ns
t _{HW}	R/W Hold Time	0	—	0	—	1	—	ns
t _{SD}	Input Data Setup Time	3.5	—	4	—	4	—	ns
t _{HD}	Input Data Hold Time	0	—	0	—	1	—	ns
t _{SAD}	\overline{ADS} Setup Time	3.5	—	4	—	4	—	ns
t _{HAD}	\overline{ADS} Hold Time	0	—	0	—	1	—	ns
t _{SCN}	\overline{CNTEN} Setup Time	3.5	—	4	—	4	—	ns
t _{HCN}	\overline{CNTEN} Hold Time	0	—	0	—	1	—	ns
t _{SRST}	\overline{CNTRST} Setup Time	3.5	—	4	—	4	—	ns
t _{HRST}	\overline{CNTRST} Hold Time	0	—	0	—	1	—	ns
t _{OE}	Output Enable to Data Valid	—	6.5	—	7.5	—	9	ns
t _{OLZ}	Output Enable to Output Low-Z ⁽¹⁾	2	—	2	—	2	—	ns
t _{OHZ}	Output Enable to Output High-Z ⁽¹⁾	1	7	1	7	1	7	ns
t _{CD1}	Clock to Data Valid (Flow-Through) ⁽²⁾	—	15	—	18	—	20	ns
t _{CD2}	Clock to Data Valid (Pipelined) ⁽²⁾	—	6.5	—	7.5	—	9	ns
t _{DC}	Data Output Hold After Clock High	2	—	2	—	2	—	ns
t _{CKHZ}	Clock High to Output High-Z ⁽¹⁾	2	9	2	9	2	9	ns
t _{CKLZ}	Clock High to Output Low-Z ⁽¹⁾	2	—	2	—	2	—	ns
Port-to-Port Delay								
t _{CWDD}	Write Port Clock High to Read Data Delay	—	24	—	28	—	35	ns
t _{COS}	Clock-to-Clock Setup Time	—	9	—	10	—	15	ns

NOTES:

5655 tbl 11

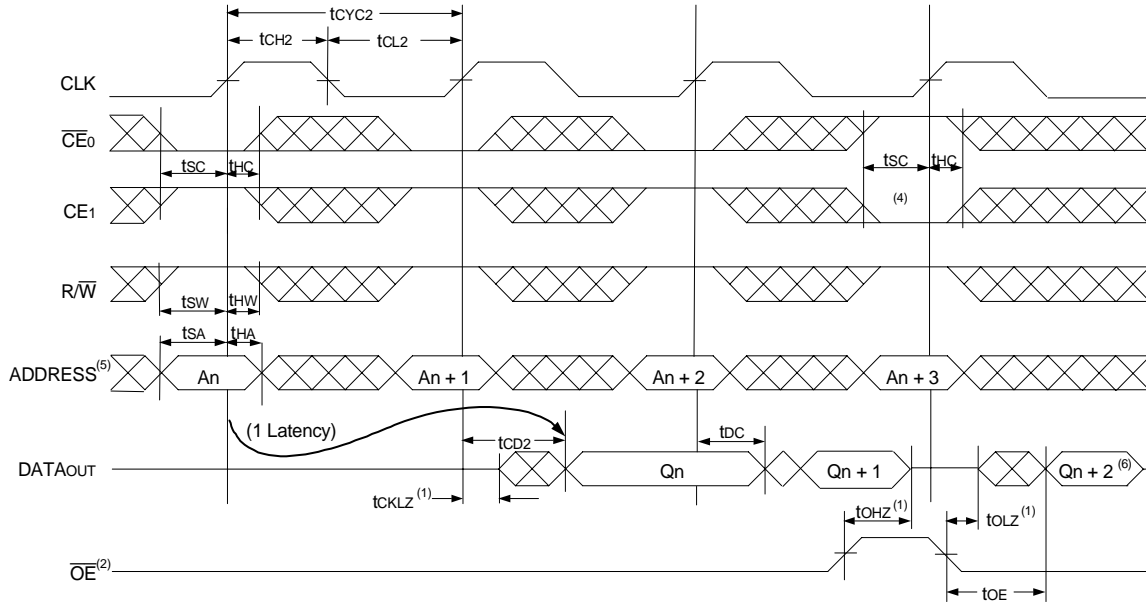
1. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2). This parameter is guaranteed by device characterization, but is not production tested.
2. The Pipelined output parameters (t_{CYC2}, t_{CD2}) apply to either or both the Left and Right ports when $\overline{FT}/PIPE = V_{IH}$. Flow-through parameters (t_{CYC1}, t_{CD1}) apply when $\overline{FT}/PIPE = V_{IL}$ for that port.
3. All input signals are synchronous with respect to the clock except for the asynchronous Output Enable (\overline{OE}), $\overline{FT}/PIPE_R$, and $\overline{FT}/PIPE_L$.

Timing Waveform of Read Cycle for Flow-Through Output ($\overline{\text{FT}}/\text{PIPE}^{\text{X}} = \text{V}_{\text{IL}}$)(3,6)



5655 drw 07

Timing Waveform of Read Cycle for Pipelined Operation ($\overline{\text{FT}}/\text{PIPE}^{\text{X}} = \text{V}_{\text{IH}}$)(3,6)

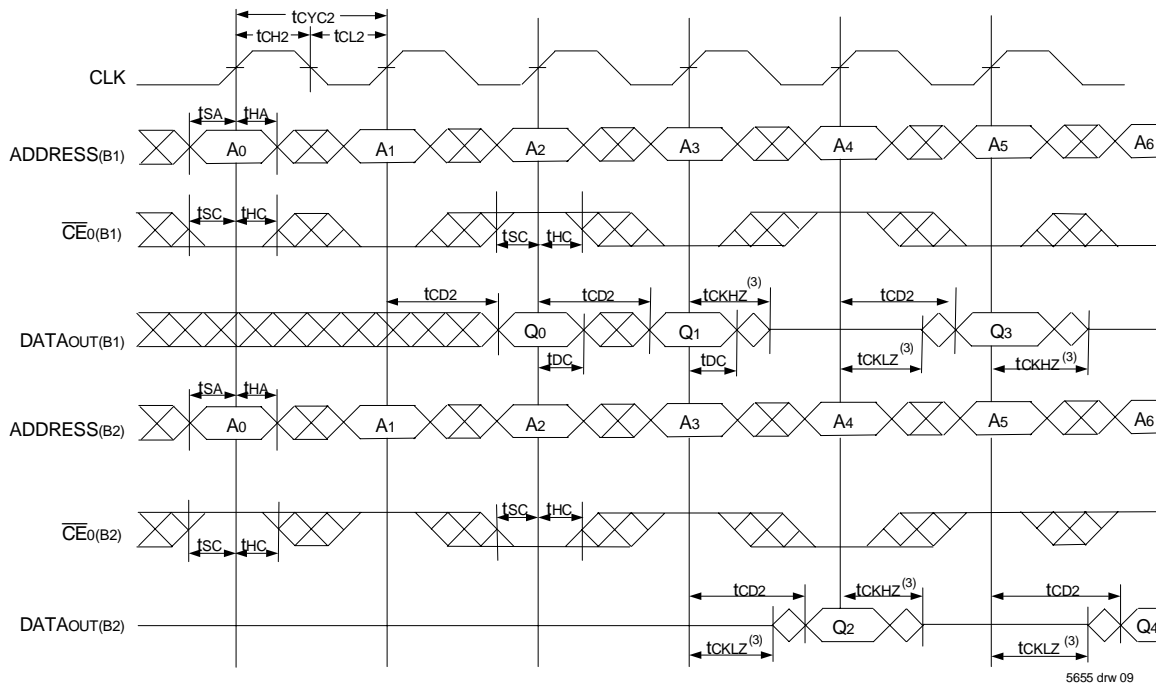


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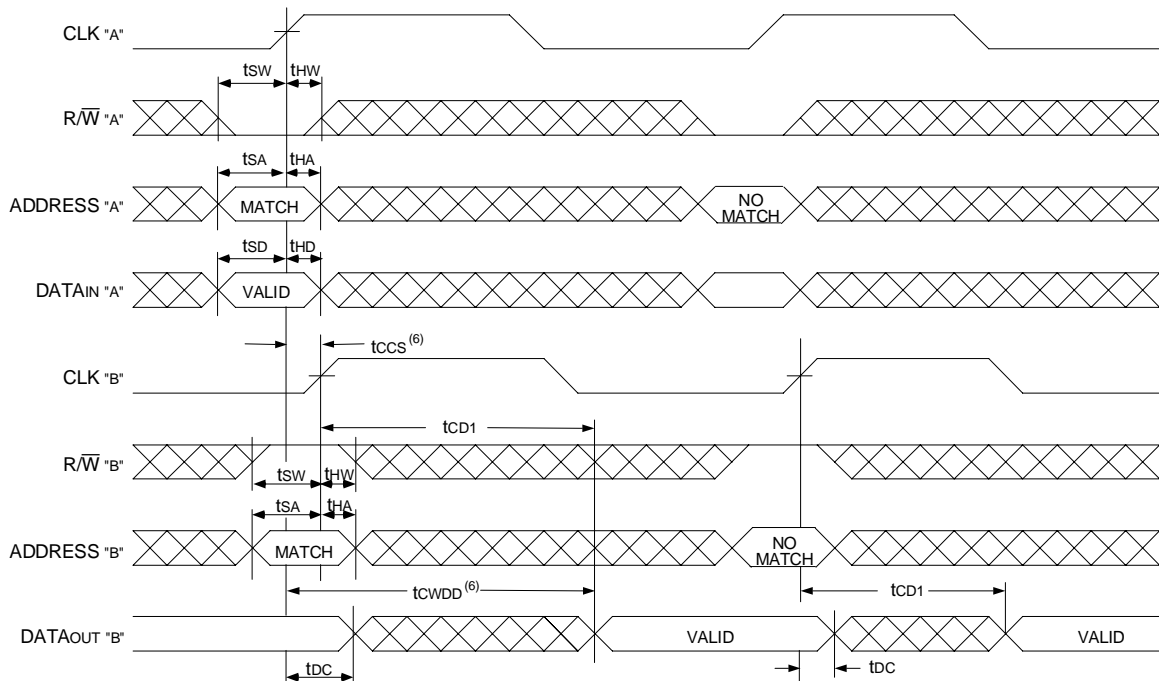
NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2).
2. $\overline{\text{OE}}$ is asynchronously controlled; all other inputs are synchronous to the rising clock edge.
3. $\overline{\text{ADS}} = \text{V}_{\text{IL}}$, $\overline{\text{CNTEN}}$ and $\overline{\text{CNRST}} = \text{V}_{\text{IH}}$.
4. The output is disabled (High-Impedance state) by $\overline{\text{CE}}_0 = \text{V}_{\text{IH}}$, $\text{CE}_1 = \text{V}_{\text{IL}}$ following the next rising edge of the clock. Refer to Truth Table 1.
5. Addresses do not have to be accessed sequentially since $\overline{\text{ADS}} = \text{V}_{\text{IL}}$ constantly loads the address on the rising edge of the CLK; numbers are for reference use only.
6. "X" here denotes Left or Right port. The diagram is with respect to that port.

Timing Waveform of a Bank Select Pipelined Read^(1,2)



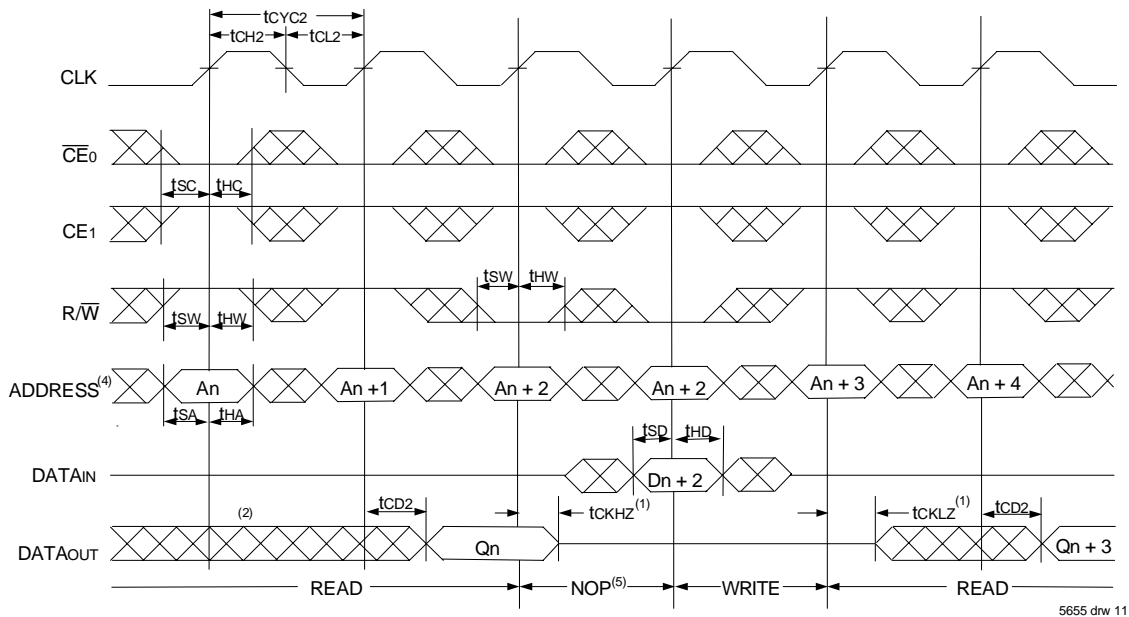
Timing Waveform with Port-to-Port Flow-Through Read^(4,5,7)



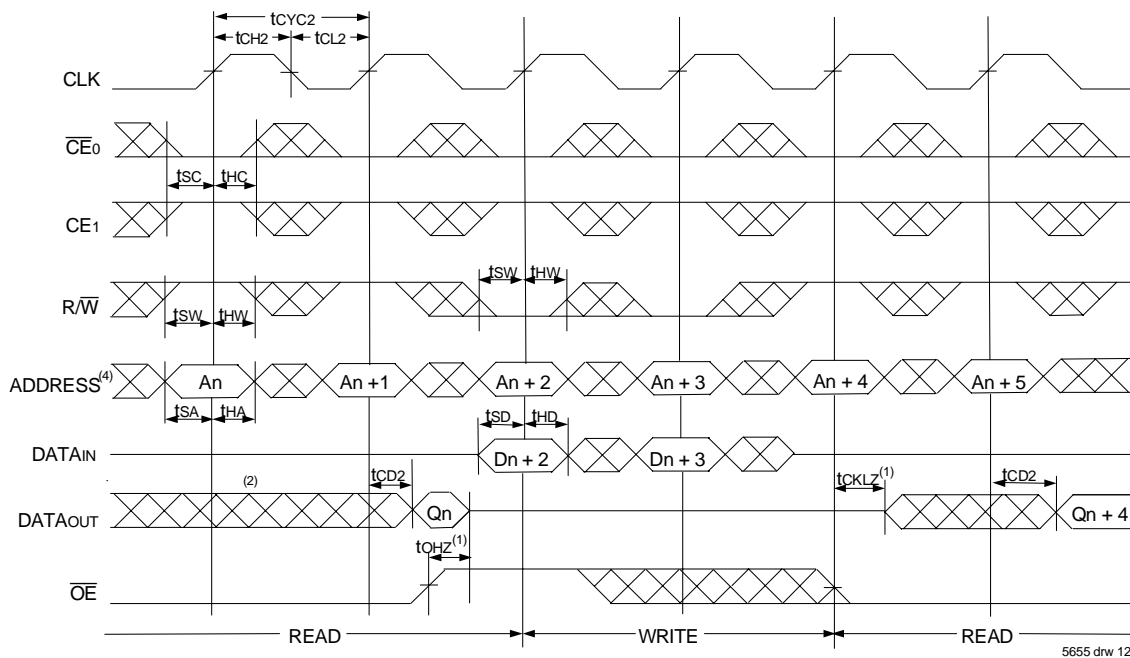
NOTES:

1. B1 Represents Bank #1; B2 Represents Bank #2. Each Bank consists of one IDT70V916/59L for this waveform, and are setup for depth expansion in this example. ADDRESS(B1) = ADDRESS(B2) in this situation.
2. \overline{OE} and $\overline{ADS} = V_{IL}$; $CE_1(B1)$, $CE_1(B2)$, R/\overline{W} , \overline{CNTEN} , and $\overline{CNTRST} = V_{IH}$.
3. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2).
4. \overline{CE}_0 and $\overline{ADS} = V_{IL}$; CE_1 , \overline{CNTEN} , and $\overline{CNTRST} = V_{IH}$.
5. $\overline{OE} = V_{IL}$ for the Right Port, which is being read from. $\overline{OE} = V_{IH}$ for the Left Port, which is being written to.
6. If $t_{CCS} \leq$ maximum specified, then data from right port READ is not valid until the maximum specified for t_{CWD} .
If $t_{CCS} >$ maximum specified, then data from right port READ is not valid until $t_{CCS} + t_{CD1}$. t_{CWD} does not apply in this case.
7. All timing is the same for both Left and Right ports. Port "A" may be either Left or Right port. Port "B" is the opposite from Port "A".

Timing Waveform of Pipelined Read-to-Write-to-Read ($\overline{OE} = V_{IL}$)⁽³⁾



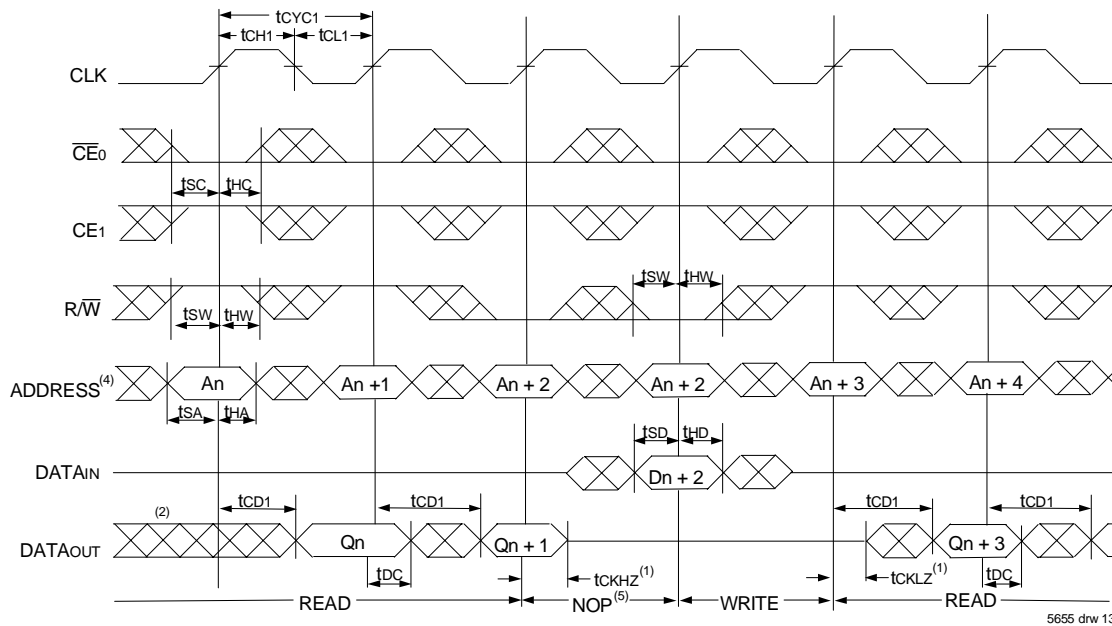
Timing Waveform of Pipelined Read-to-Write-to-Read (\overline{OE} Controlled)⁽³⁾



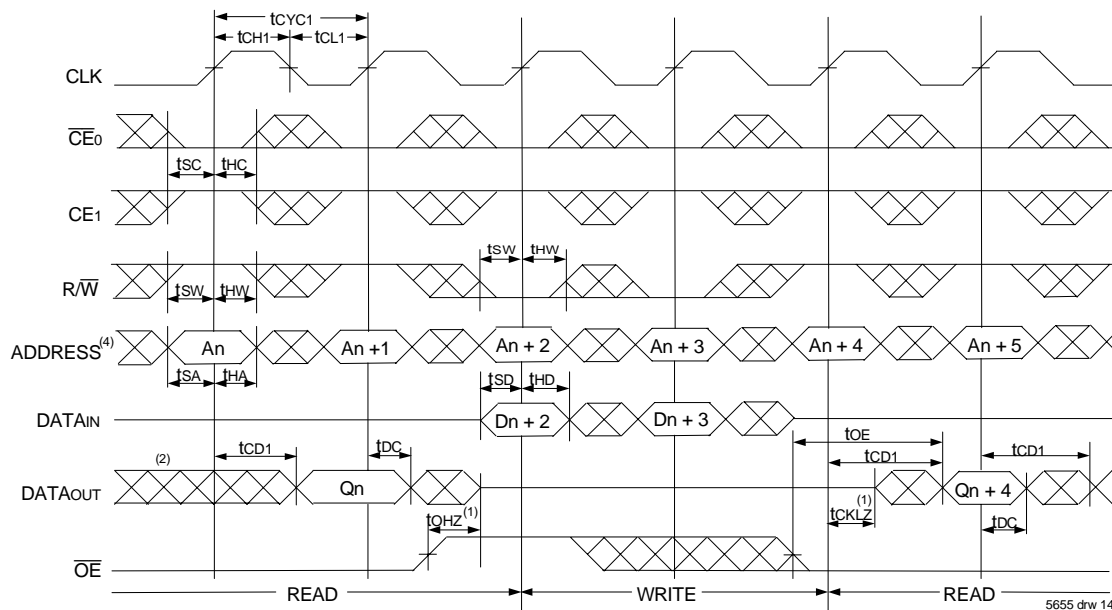
NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2).
2. Output state (High, Low, or High-impedance) is determined by the previous cycle control signals.
3. $\overline{CE0}$ and $\overline{ADS} = V_{IL}$; $\overline{CE1}$, \overline{CNTEN} , and $\overline{CNRST} = V_{IH}$. "NOP" is "No Operation".
4. Addresses do not have to be accessed sequentially since $\overline{ADS} = V_{IL}$ constantly loads the address on the rising edge of the CLK; numbers are for reference use only.
5. "NOP" is "No Operation." Data in memory at the selected address may be corrupted and should be re-written to guarantee data integrity.

Timing Waveform of Flow-Through Read-to-Write-to-Read ($\overline{OE} = V_{IL}$)⁽³⁾



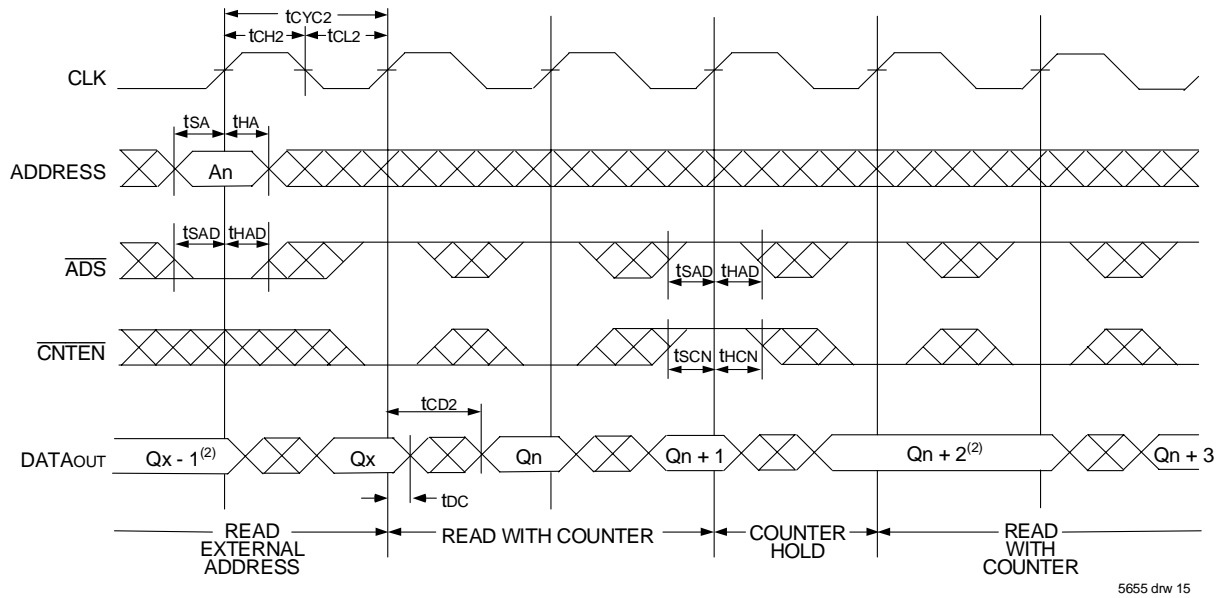
Timing Waveform of Flow-Through Read-to-Write-to-Read (\overline{OE} Controlled)⁽³⁾



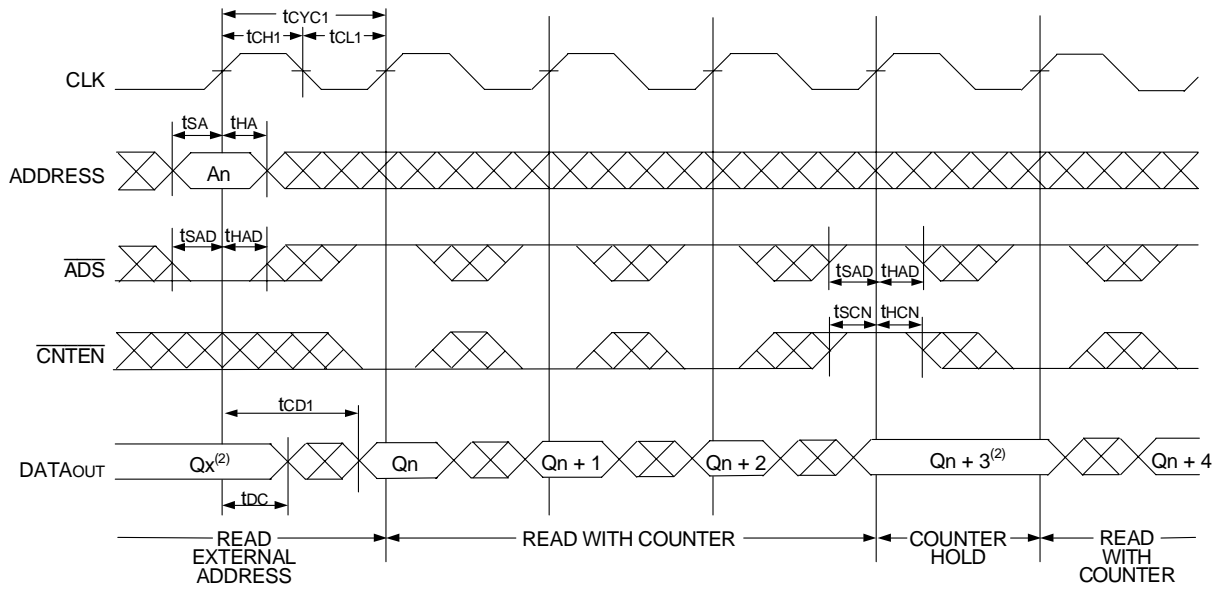
NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2).
2. Output state (High, Low, or High-impedance) is determined by the previous cycle control signals.
3. $\overline{CE0}$ and $\overline{ADS} = V_{IL}$; $\overline{CE1}$, \overline{CNTEN} , and $\overline{CNTRST} = V_{IH}$. "NOP" is "No Operation".
4. Addresses do not have to be accessed sequentially since $\overline{ADS} = V_{IL}$ constantly loads the address on the rising edge of the CLK; numbers are for reference use only.
5. "NOP" is "No Operation." Data in memory at the selected address may be corrupted and should be re-written to guarantee data integrity.

Timing Waveform of Pipelined Read with Address Counter Advance⁽¹⁾



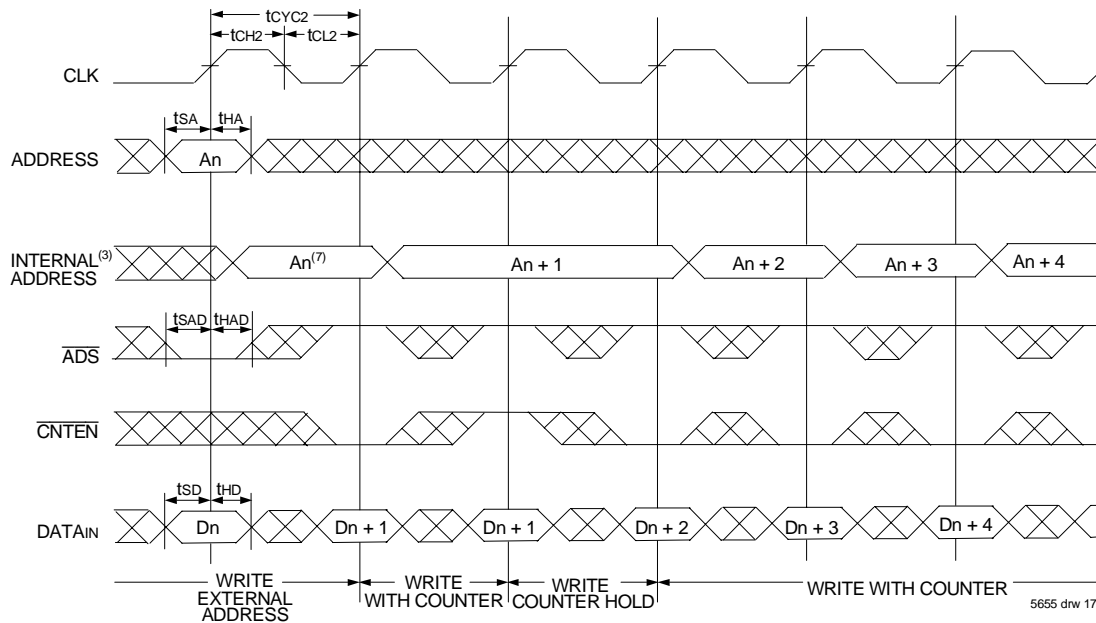
Timing Waveform of Flow-Through Read with Address Counter Advance⁽¹⁾



NOTES:

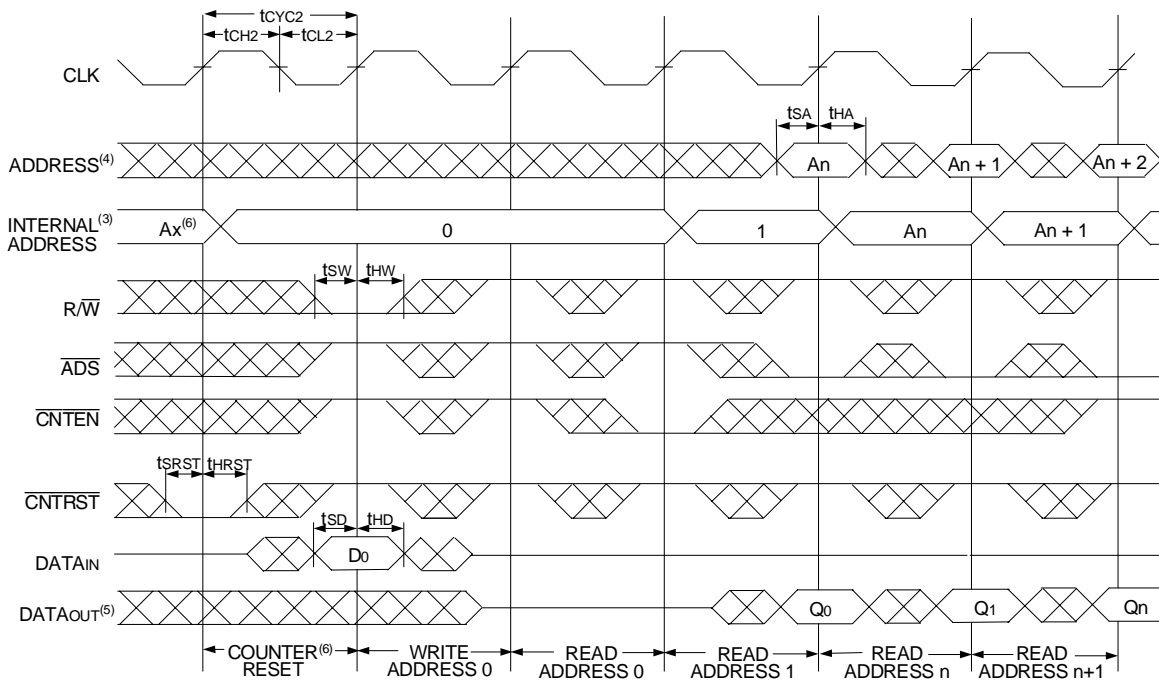
1. $\overline{CE_0}$ and $\overline{OE} = V_{IL}$; CE_1 , $R\overline{W}$, and $\overline{CNTEN} = V_{IH}$.
2. If there is no address change via $ADS = V_{IL}$ (loading a new address) or $\overline{CNTEN} = V_{IL}$ (advancing the address), i.e. $\overline{ADS} = V_{IH}$ and $\overline{CNTEN} = V_{IH}$, then the data output remains constant for subsequent clocks.

Timing Waveform of Write with Address Counter Advance (Flow-Through or Pipelined Outputs)⁽¹⁾



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Timing Waveform of Counter Reset (Pipelined Outputs)⁽²⁾



NOTES:

1. $\overline{CE_0}$ and $R/\overline{W} = V_{IL}$; CE_1 and $\overline{CNTRST} = V_{IH}$.
2. $\overline{CE_0} = V_{IL}$; $CE_1 = V_{IH}$.
3. The "Internal Address" is equal to the "External Address" when $\overline{ADS} = V_{IL}$ and equals the counter output when $\overline{ADS} = V_{IH}$.
4. Addresses do not have to be accessed sequentially since $\overline{ADS} = V_{IL}$ constantly loads the address on the rising edge of the CLK; numbers are for reference use only.
5. Output state (High, Low, or High-impedance) is determined by the previous cycle control signals.
6. No dead cycle exists during counter reset. A READ or WRITE cycle may be coincidental with the counter reset cycle. $ADDR_0$ will be accessed. Extra cycles are shown here simply for clarification.
7. $\overline{CNTEN} = V_{IL}$ advances Internal Address from ' A_n ' to ' $A_n + 1$ '. The transition shown indicates the time required for the counter to advance. The ' $A_n + 1$ ' Address is written to during this cycle.

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Functional Description

The IDT70V9169/59 provides a true synchronous Dual-Port Static RAM interface. Registered inputs provide minimal set-up and hold times on address, data, and all critical control inputs. All internal registers are clocked on the rising edge of the clock signal, however, the self-timed internal write pulse is independent of the LOW to HIGH transition of the clock signal.

An asynchronous output enable is provided to ease asynchronous bus interfacing. Counter enable inputs are also provided to stall the operation of the address counters for fast interleaved memory applications.

$\overline{CE_0} = V_{IL}$ and $CE_1 = V_{IH}$ for one clock cycle will power down the internal circuitry to reduce static power consumption. Multiple chip enables allow easier banking of multiple IDT70V9169/59's for depth expansion configurations. When the Pipelined output mode is enabled, two cycles are required with $\overline{CE_0} = V_{IL}$ and $CE_1 = V_{IH}$ to re-activate the outputs.

Depth and Width Expansion

The IDT70V9169/59 features dual chip enables (refer to Truth Table I) in order to facilitate rapid and simple depth expansion with no requirements for external logic. Figure 4 illustrates how to control the various chip enables in order to expand two devices in depth.

The IDT70V9169/59 can also be used in applications requiring expanded width, as indicated in Figure 4. Since the banks are allocated at the discretion of the user, the external controller can be set up to drive the input signals for the various devices as required to allow for 36-bit or wider applications.

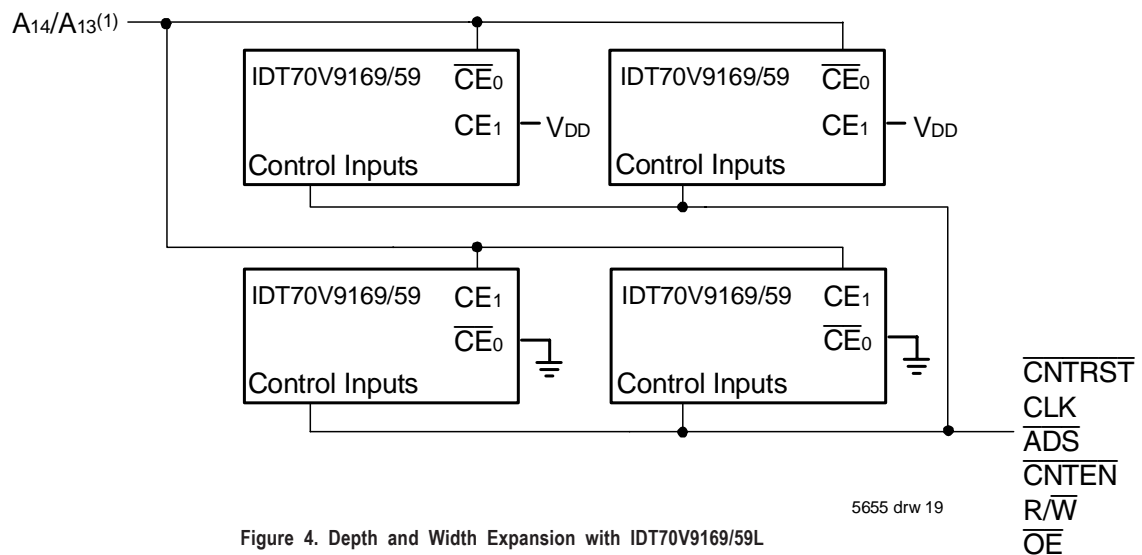


Figure 4. Depth and Width Expansion with IDT70V9169/59L

NOTE:

1. A14 is for IDT70V9169, A13 is for IDT70V9159.

Ordering Information

IDT	XXXXX	A	99	A	A		
	Device Type	Power	Speed	Package	Process/ Temperature Range		
						Blank I ⁽¹⁾	Commercial (0°C to +70°C) Industrial (-40°C to +85°C)
						PF BF	100-pin TQFP (PN100-1) 100-pin fpBGA (BF100)
						6 7 9	Commercial Only Commercial & Industrial Commercial Only
						L	Low Power
						70V9169	144K (16K x 9-Bit) Synchronous Dual-Port RAM
						70V9159	72K (8K x 9-Bit) Synchronous Dual-Port RAM

NOTE:

1. Contact your local sales office for Industrial temp range for other speeds, packages and powers.

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IDT Clock Solution for IDT70V9169/59 Dual-Port

IDT Dual-Port Part Number	Dual-Port I/O Specifications		Clock Specifications				IDT PLL Clock Device	IDT Non-PLL Clock Device
	Voltage	I/O	Input Capacitance	Input Duty Cycle Requirement	Maximum Frequency	Jitter Tolerance		
70V9169/59	3.3	LVTTTL	9pF	40%	100	150ps	IDT2305 IDT2308 IDT2309	FCT3805 FCT3805D/E FCT3807 FCT3807D/E

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Datasheet Document History

07/08/02: Initial Public Release
08/15/03: Removed Preliminary status
Page 16 Added IDT Clock Solution Table



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